# EHB 335 E HW#4

#### Grilce BAYSAL 040170051

$$V_{8650} = 0.7V$$

$$V_{652} = 0.2V$$

$$V_{A} = \infty$$

$$V_{7} = -1.8V$$

$$V_{7} = 1.2 \text{ mA}/V^{2}$$

$$V_{7} = \sqrt{2}$$

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a) Determine Volutimax & Volutimin and the corresponding input voltages for the circuit operate in Class-A region for -> RL=00 -> RL=50012.

When Vin > VBE -> Vart, max = VCC-VCE, set = 4,8V When Vm < VBE -> BUT is off -> Vartmm = -I.P.L Lo I, Ib = 12:10-3. (Vgs-VT)2 = 38,9mA

b) What is the smallest value of RL possible it a 2V peak sine wave is produced at the output?

Pav = 
$$(Vcc-VP_{|2})II = VccII - \frac{Vp^2}{2RL}$$
  $IpVp=II.RL$ 
 $4 \cdot II = 5II - \frac{4}{2RL}$ 
 $RL.II = 2V$ 
 $RL = \frac{2}{II} = \frac{2}{88.98} \times 10^{-3} = 51.4 \cdot 2L$ 

c) What is the corresponding power conversion efficiency?

Consider the class-AB output stage in Figure. Assume all transistors are matched, with parameters V+=V-=12V and 3=40, Vee (npn) = Vee (pnp) = 0,7V, R1=R2=250.1, R3=R4=0.1, R1=8.1

a) For GI=04 determine (E,, (E2, ie, diB2.

$$\alpha = \frac{\beta}{1+\beta} = \frac{40}{41}$$

12 - RI. (iEI+ (B3) = 0) 7V

$$\frac{1113}{250} = ie2 - i04$$

$$\frac{1113}{250} = ie2 + i04$$

$$\frac{1113}{250} = ie2 + i04$$

$$\frac{1113}{41} = ie2 + i04$$

b) For 41=5V determine (I) to, i EldiEz, i BldiBz.

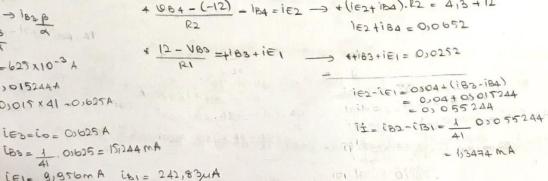
$$+\frac{(084-(-12))}{82} = 184 = 182 \longrightarrow +(182+184).82 = 418+12$$

iEI= 9,950mA ib1 = 242,83MA CE2 = 67,2mt (B2 = 1,6m4

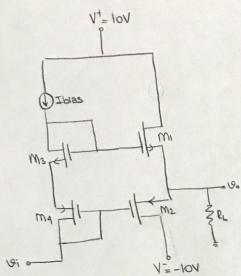
10=629mA in= 1,3474mA

c) Current gain = ?

$$\frac{10}{Cin} = \frac{01625}{1,3474\times10^{-3}} = 463,876316$$



Consider the class-AB MOSFET Output stage in Figure. I bize = 012mA, RL = 1kQ, VTH, n = 08V, K'n = 100 MA 1V2, VTH, p = -018V, K'p = 40 MA 1V2 For the quiescent condition, assume  $V_{GS13} = V_{SG34}$ ,  $\lambda = 0$  for all transistors. VGS,1 = VGS,2



b) Assuming voltage drop across I was of 0.2 V, Vi=-1,TV

find the max and min umits of Vo. Vomax = 1+ - Vovada) - VEIST = 10-02-115 = 8,34 Vomary 2 = Y+ VDS, 1 = 10-0,7 = 913V , FO = NGS = VTh = O,7 Nommi = V - 1 VSD,2 = -8,34 Vomin 2 = Vov(in) + (VSG)21 = 0 0 & Vo & 813 V ,,

a) If Vi=-15V, Vo= OV, io1=102 = 015mA; determine WIL VI=-1,5V => V52=0V VG1 2 = VD4 = Vi = -1554 VSG2 = VGSI = 1,5V  $io_1=io_2=0.5=\frac{0.1}{2}(\frac{W}{L})_{1}(\frac{VGSI-VTH20}{(115-018)^2}$ (M) = 20,4/1 015 = 0104 (W)2.0149 (W) 2=51/1 VE3= VE1 =1,5V => VG4= 01 VS4 = VS3 NG3 VS b = VS4 - NG4 11x-V53 = V53+KF VS= VS4 = 0 VG53=V5G4=1,5V Ibias= 0,2= 0,1 (4)3 (1,5-0,8)2

4 = (4)3.0,49

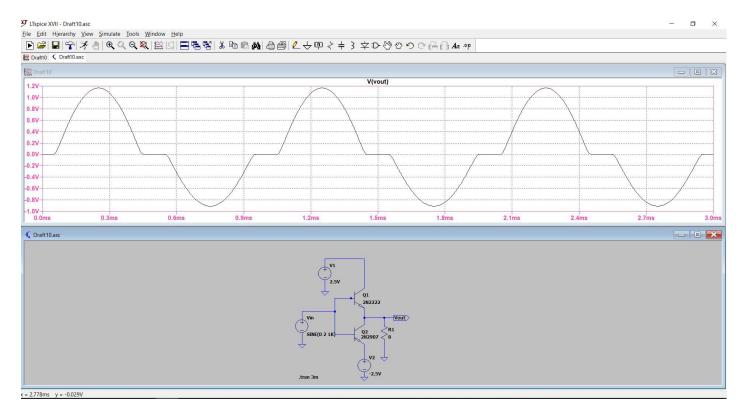
0,2= 0,04 ( 1)4.0,49

(M) 3= 814p 11

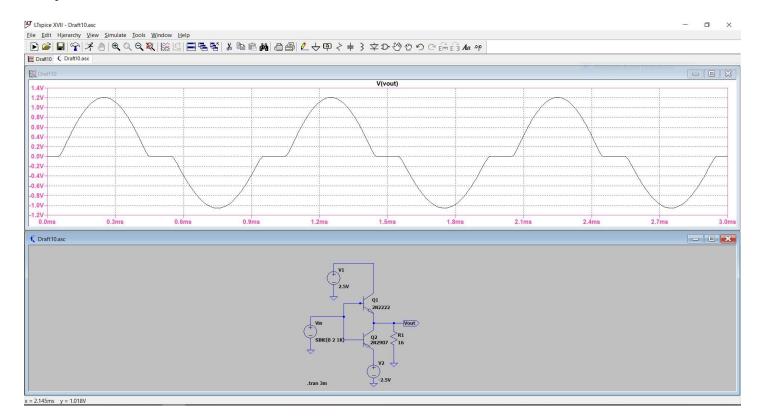
(M) 4 = 20) A/

### **Question 4**

## a) When R= 8 ohms



### b) When R=16 ohms



-> When the value of R increases, Vout\_max increases but the Vout\_min decreases.